

RO3073

**315.0 MHz
SAW
Resonator**



- Ideal for 315.0 MHz Transmitters
- Low Series Resistance
- Quartz Stability
- Rugged, Hermetic, Low-Profile TO39 Case
- Complies with Directive 2002/95/EC (RoHS)



The RO3073 is a true one-port, surface-acoustic-wave (SAW) resonator in a low-profile TO39 case. It provides reliable, fundamental-mode, quartz frequency stabilization of fixed-frequency transmitters operating at 315 MHz. The RO3073 is designed specifically for wireless remote controls and security transmitters, typically for automotive-keyless-entry, operating in the USA under FCC Part 15, in Canada under DoC RSS-210, and in Italy.

Absolute Maximum Ratings

Rating	Value	Units
CW RF Power Dissipation (See Typical Test Circuit)	+0	dBm
DC Voltage Between Any Two Pins (Observe ESD Precautions)	±30	VDC
Case Temperature	-40 to +85	°C
Soldering Temperature (10 seconds/5 cycles Max)	260	°C

Electrical Characteristics

Characteristic	Sym	Notes	Minimum	Typical	Maximum	Units
Center Frequency (+25 °C) Absolute Frequency	f_C	2, 3, 4, 5	314.925		315.075	MHz
	Δf_C				±75	kHz
Insertion Loss	IL	2, 5, 6		1.5	2.2	dB
	Q_U		5, 6, 7		7800	
Quality Factor	Q_L				1100	
	Temperature Stability	T_O	6, 7, 8	10	25	40
f_O				f_C		kHz
FTC				0.037		ppm/°C ²
Frequency Aging	$ f_A $	1		≤10		ppm/yr
DC Insulation Resistance between Any Two Pins		5	1.0			MΩ
RF Equivalent RLC Model	R_M	5, 7, 9		16		Ω
	L_M			63		μH
	C_M			4.1		fF
	C_O		5, 6, 9	3.6		pF
Transducer Static Capacitance	C_P	5, 6, 7, 9		3.6		pF
Test Fixture Shunt Inductance	L_{TEST}	2, 7		65.7		nH
Lid Symbolization (in Addition to Lot and/or Date Codes)	RFM RO3073					



CAUTION: Electrostatic Sensitive Device. Observe precautions for handling.

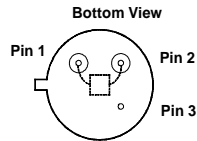
NOTES:

1. Frequency aging is the change in f_C with time and is specified at +65°C or less. Aging may exceed the specification for prolonged temperatures above +65°C. Typically, aging is greatest the first year after manufacture, decreasing significantly in subsequent years.
2. The center frequency, f_C , is measured at the minimum insertion loss point, IL_{MIN} , with the resonator in the 50 Ω test system (VSWR ≤ 1.2:1). The shunt inductance, L_{TEST} , is tuned for parallel resonance with C_O at f_C . Typically, $f_{OSCILLATOR}$ or $f_{TRANSMITTER}$ is less than the resonator f_C .
3. One or more of the following United States patents apply: 4,454,488 and 4,616,197 and others pending.
4. Typically, equipment designs utilizing this device require emissions testing and government approval, which is the responsibility of the equipment manufacturer.
5. Unless noted otherwise, case temperature $T_C = +25°C ± 2°C$.
6. The design, manufacturing process, and specifications of this device are subject to change without notice.
7. Derived mathematically from one or more of the following directly measured parameters: f_C , IL , 3 dB bandwidth, f_C versus T_C , and C_O .
8. Turnover temperature, T_O , is the temperature of maximum (or turnover) frequency, f_O . The nominal frequency at any case temperature, T_C , may be calculated from: $f = f_O [1 - FTC (T_O - T_C)^2]$. Typically, oscillator T_O is 20°C less than the specified resonator T_O .
9. This equivalent RLC model approximates resonator performance near the resonant frequency and is provided for reference only. The capacitance C_O is the static (nonmotional) capacitance between pin1 and pin 2 measured at low frequency (10 MHz) with a capacitance meter. The measurement includes case parasitic capacitance with a floating case. For usual grounded case applications (with ground connected to either pin 1 or pin 2 and to the case), add approximately 0.25 pF to C_O .

Electrical Connections

This one-port, two-terminal SAW resonator is bidirectional. The terminals are interchangeable with the exception of circuit board layout.

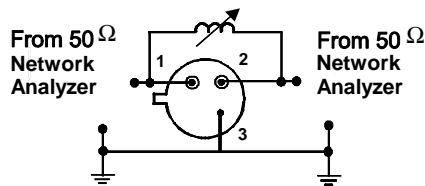
Pin	Connection
1	Terminal 1
2	Terminal 2
3	Case Ground



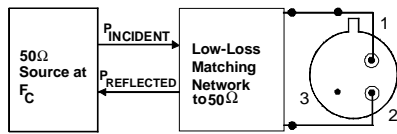
Typical Test Circuit

The test circuit inductor, L_{TEST} , is tuned to resonate with the static capacitance, C_O at F_C .

Electrical Test:



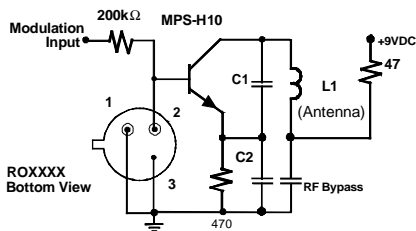
Power Test:



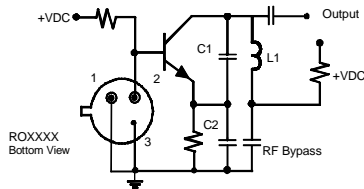
$$CW \text{ RF Power Dissipation} = P_{INCIDENT} - P_{REFLECTED}$$

Typical Application Circuits

Typical Low-Power Transmitter Application:

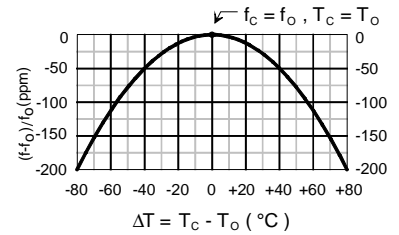


Typical Local Oscillator Application:



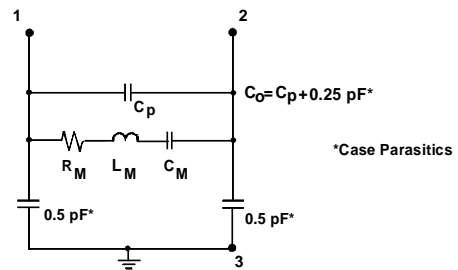
Temperature Characteristics

The curve shown on the right accounts for resonator contribution only and does not include oscillator temperature characteristics.

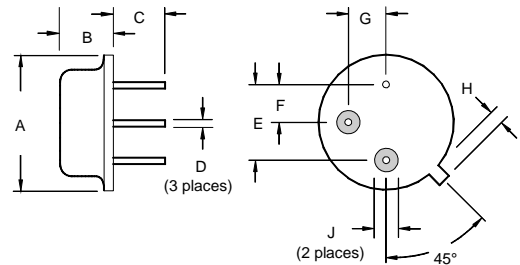


Equivalent LC Model

The following equivalent LC model is valid near resonance:



Case Design



Dimensions	Millimeters		Inches	
	Min	Max	Min	Max
A		9.40		0.370
B		3.18		0.125
C	2.50	3.50	0.098	0.138
D	0.46 Nominal		0.018 Nominal	
E	5.08 Nominal		0.200 Nominal	
F	2.54 Nominal		0.100 Nominal	
G	2.54 Nominal		0.100 Nominal	
H		1.02		0.040
J	1.40		0.055	

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

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